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SHELDON S. L. CHANG, EDITOR

CHI-TSONG CHEN, EDITOR

Department of Electrical Engineering
State University of New York at Stony Brook

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GARY THOMAS, EDITOR

Vice President for Academic Affairs
New Jersey Institute of Technology, Newark

HANG-SHENG TUAN, EDITOR

Department of Electrical Engineering
State University of New York at Stony Brook

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SHELDON S. L. CHANG, EDITOR
CHI-TSONG CHEN, EDITOR
Department of Electrical Engineering
State University of New York at Stony Brook
B. W. DANIELS
Bell Telephone Laboratories
North Andover, Massachusetts

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KENNETH STEIGLITZ, EDITOR
Department of Electrical Engineering and Computer Science
Princeton University, Princeton, New Jersey

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HANG-SHENG TUAN, EDITOR

Department of Electrical Engineering
State University of New York at Stony Brook

HENRY L. BERTONI

Department of Electrical Engineering
Polytechnic Institute of New York, Brooklyn

JAYANT KUMAR P. PAREKH

Department of Electrical Engineering
State University of New York at Stony Brook

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SECTION 6
ELECTRONICS

G. THOMAS, EDITOR

Vice President for Academic Affairs
New Jersey Institute of Technology, Newark

NARENDRA MOHAN
Department of Electrical Engineering
University of Minnesota, Minneapolis

ROBERT L. KUSTOM
Argonne National Laboratory
Argonne, Illinois

KENNETH SOHN
Department of Electrical Engineering
New Jersey Institute of Technology, Newark

S. Y. YU

J. A. CALVIELLO
Eaton Corporation
AIL Division
Melville, New York

DENNY D. TANG, T.J.
IBM Thomas J. Watson Research Center
Yorktown, New York

ANDRES FORTINO
College of Engineering Technology
Temple University, Philadelphia

MAURO ZAMBUTO
Department of Electrical Engineering
New Jersey Institute of Technology, Newark

HSU CHANG
IBM Thomas J. Watson Research Center
Yorktown, New York

W. ANACKER
IBM Thomas J. Watson Research Center
Yorktown, New York

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SHELDON S. L. CHANG, EDITOR
Department of Electrical Engineering
State University of New York at Stony Brook

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